



ON Semiconductor®

ON Semiconductor DATA SHEET

6LN04MH — N-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- 1.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		60	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		200	mA
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	800	mA
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm²×0.8mm)	0.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0V	60			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =100μA	0.4		1.3	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =100mA	280	480		mS
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =100mA, V _{GS} =4V		2.2	2.9	Ω
	R _{DS(on)2}	I _D =50mA, V _{GS} =2.5V		2.4	3.4	Ω
	R _{DS(on)3}	I _D =10mA, V _{GS} =1.5V		3.5	7.0	Ω
Input Capacitance	C _{iss}	V _{DS} =20V, f=1MHz		26		pF
Output Capacitance	C _{oss}	V _{DS} =20V, f=1MHz		5.9		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =20V, f=1MHz		3.2		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		18.5		ns
Rise Time	t _r	See specified Test Circuit.		26		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		146		ns
Fall Time	t _f	See specified Test Circuit.		69		ns

Marking : FA

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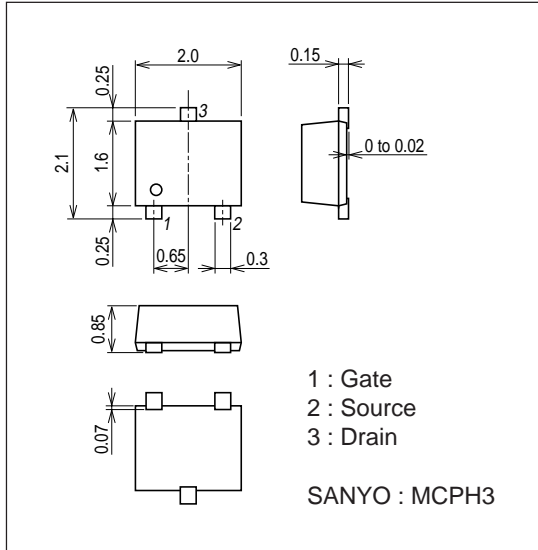
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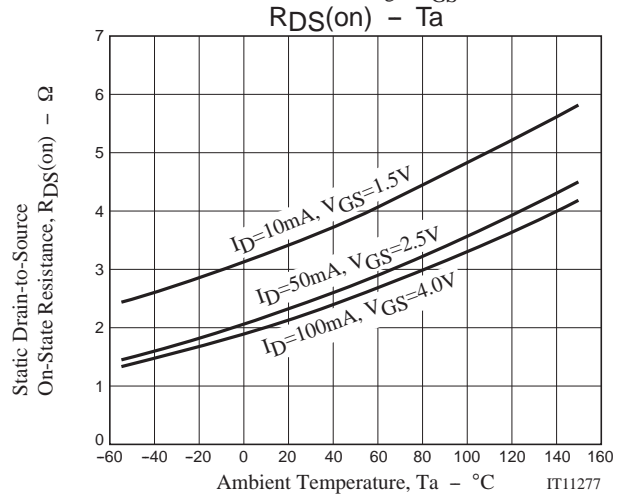
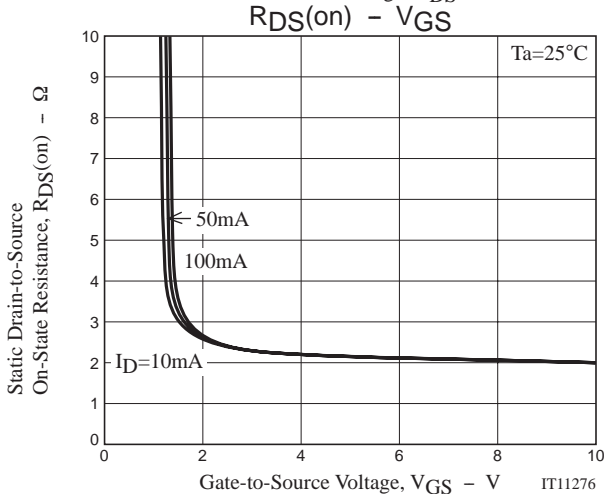
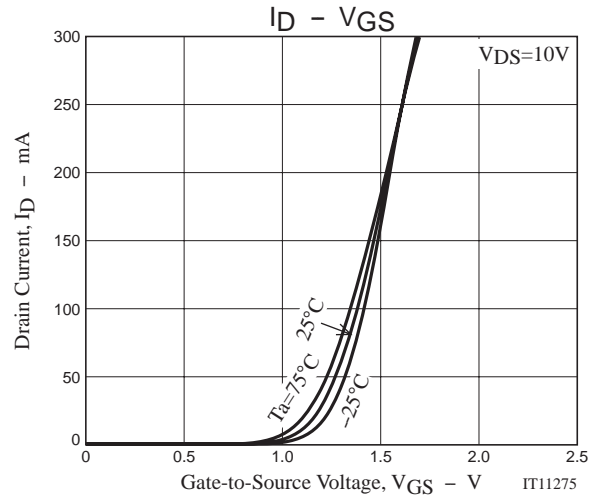
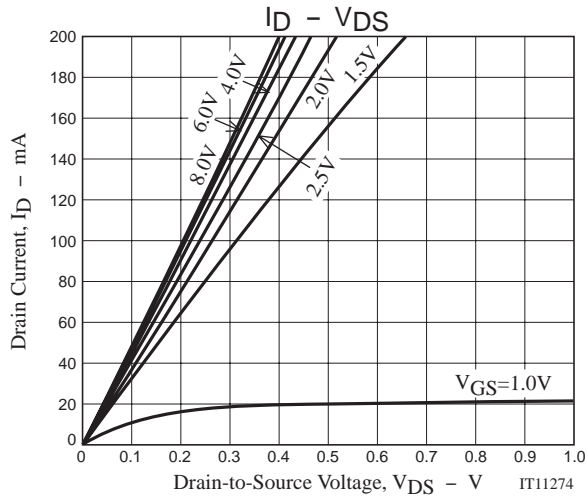
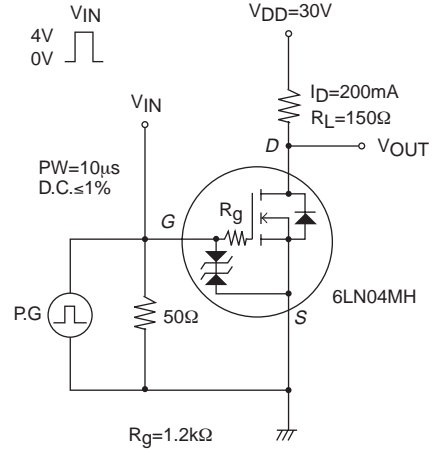
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =4V, I _D =200mA		1.0		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =4V, I _D =200mA		0.2		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =4V, I _D =200mA		0.2		nC
Diode Forward Voltage	V _{SD}	I _S =200mA, V _{GS} =0V		0.83	1.2	V

Package Dimensions

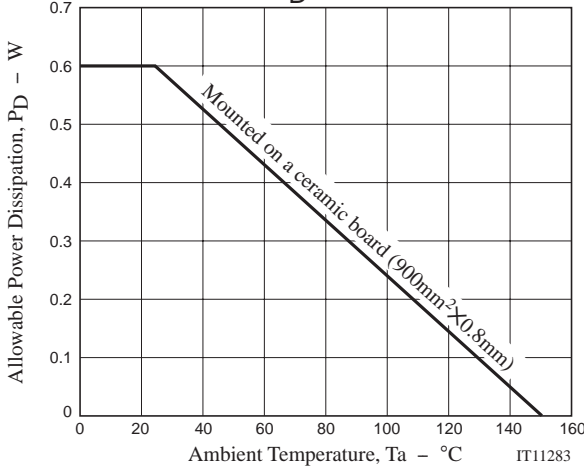
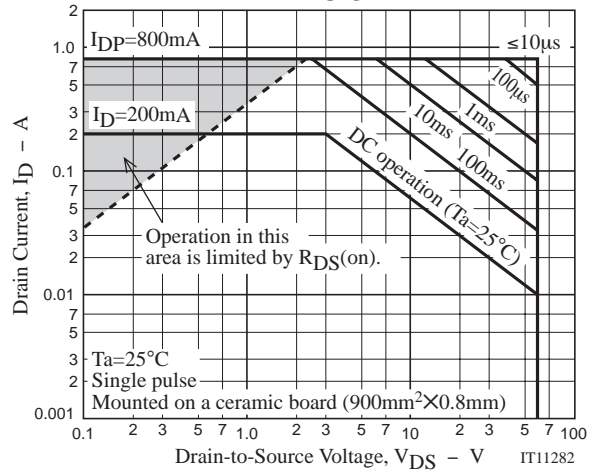
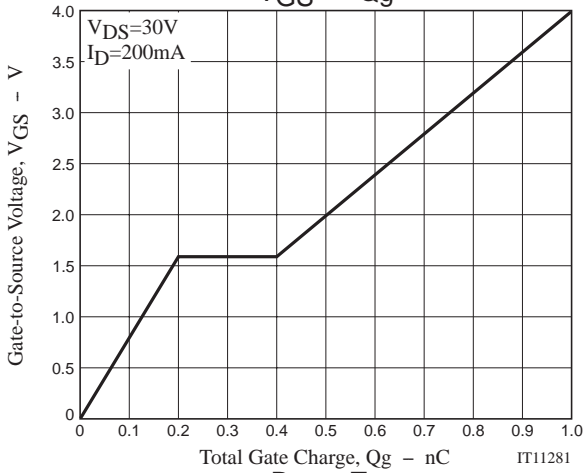
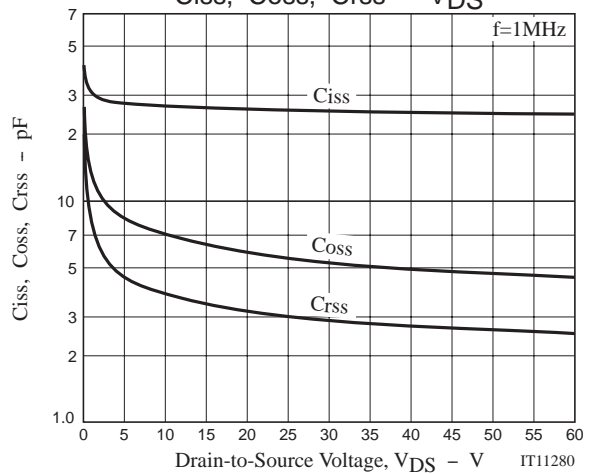
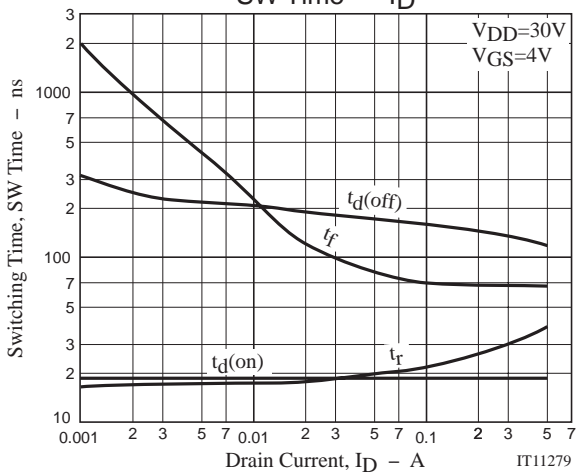
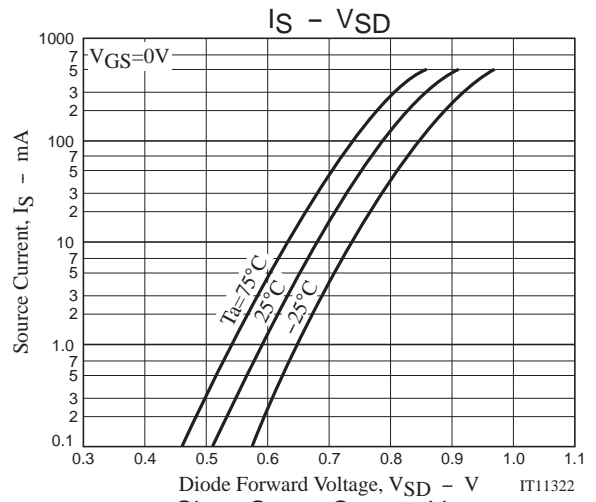
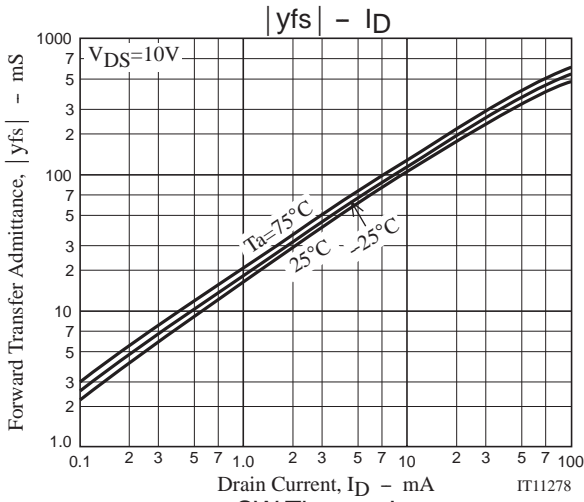
unit : mm (typ)
7019A-003



Switching Time Test Circuit



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